2SB852K / 2SA830S

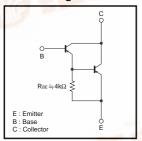
Transistors

High-gain Amplifier Transistor (–32V, –0.3A) 2SB852K / 2SA830S

Features

- 1) Darlington connection for high DC current gain.
- 2) Built-in $4k\Omega$ resistor between base and emitter.
- 3) Complements the 2SD1383K / 2SD1645S.

●Circuit diagram

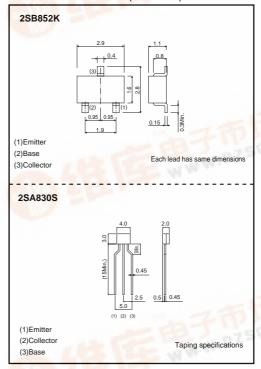


Packaging specifications

Туре	2SB852K	2SA830S
Package	SMT3	SPT
hFE	В	В
Marking	U*	_
Code	T146	TP
Basic ordering unit (pieces)	3000	5000

^{*} Denotes hre

●External dimensions (Unit: mm)



● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit		
Collector-base voltage		Vсво	-40	V		
Collector-emitter voltage		Vces	-32	V *		
Emitter-base voltage		Vево	-6	V		
Collector current		Ic	-0.3	Α		
Collector power dissipation	2SB852K	Pc	0.2	W		
	2SA830S	PC	0.3			
Junction temperature		Tj	150	°C		
Storage temperature		Tstg	-55 to +150	°C		

 $^{*\;\}mathsf{R}_\mathsf{BE}\!\!=\!\!0\Omega$



●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-40	_	_	V	Ic=-100μA
Collector-emitter breakdown voltage	BVces	-32	_	-	V	Ic=-1mA
Emitter-base breakdown voltage	ВVево	-6	_	_	V	IE= -100μA
Collector cutoff current	Ісво	_	_	-1	μΑ	Vcb= -24V
Emitter cutoff current	Ієво	_	_	-1	μΑ	V _{EB} = -4.5V
DC current transfer ratio	hfe	5000	_	-	_	Vce=-5V, Ic=-0.1A
Collector-emitter saturation voltage	VCE(sat)	_	_	-1.5	V	Ic= -200mA, I _B = -0.4mA *1
Transition frequency	f⊤	_	200	_	MHz	Vc=-5V, I=10mA, f=100MHz *2
Output capacitance	Cob	_	3	_	pF	Vсв= −10V, I∈=0A, f=1MHz

Electrical characteristic curves

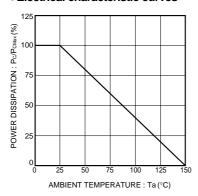


Fig.1 Power dissipation curves

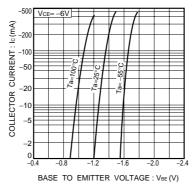


Fig.2 Ground emitter propagation characteristisc

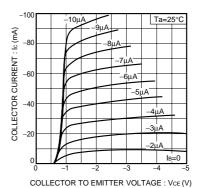


Fig.3 Ground emitter output characteristics

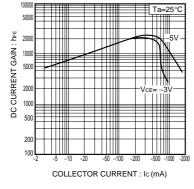


Fig.4 DC current gain vs. collector current (I)

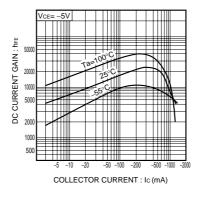


Fig.5 DC current gain vs. collector current ($\rm II$)

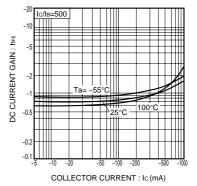


Fig.6 Collector-emitter saturation voltage vs. collector current

^{*1} Measured using pulse current. *2 Transition frequency of the device.

Transistors

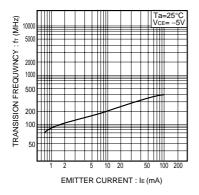


Fig.7 Gain bandwidth product vs. emitter current

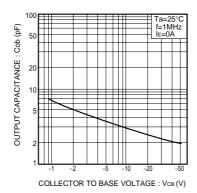


Fig.8 Collector output capacitance vs. collector-base voltage

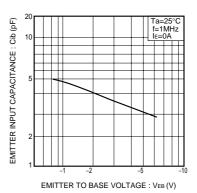


Fig.9 Emitter input capacitance vs. emitter-base voltage

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